# NSN 5962-01-283-9166

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# **Body Length:**

1.290 inches

## **Body Width:**

0.600 inches

# **Body Height:**

0.180 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

High performance and schottky and high speed and high reliability and multichip and low power and 3-state output and monolithic and

bipolar and electrostatic sensitive and hermetically sealed and programmable

#### **Inclosure Material:**

Ceramic

## Inclosure Configuration:

Dual-in-line

# **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

14 input

# **Current Rating Per Characteristic:**

185.00 milliamperes reverse current, dc absolute

# **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

5.0 volts power source

# **Capitance Rating Per Characteristic:**

12.00 output picofarads

#### **Time Rating Per Chacteristic:**

55.00 nanoseconds access

## Memory Device Type:

Prom

#### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## **Terminal Type And Quantity:**

24 printed circuit

## Shelf Life:

N/a

## Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

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